

SMS05C, SMS12C, SMS15C, SMS24C

5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single TSOP-6 package.

Features

- Protects up to 5 Lines in a Single TSOP-6 Package
- Peak Power Dissipation – 350 W ($8 \times 20 \mu\text{s}$ Waveform)
- ESD Rating of Class 3B (Exceeding 8.0 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8.0 kV (Contact)
- Flammability Rating of UL 94 V-0
- These are Pb-Free Devices

Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Rating	Value	Unit
$P_{PK} 1$	Peak Power Dissipation $8 \times 20 \mu\text{s}$ Double Exponential Waveform (Note 1)	350	W
T_J	Operating Junction Temperature Range	-40 to 150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_L	Lead Solder Temperature (10 s)	260	$^\circ\text{C}$
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	>8000 >400 >15000 >8000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Non-repetitive current pulse per Figure 3.

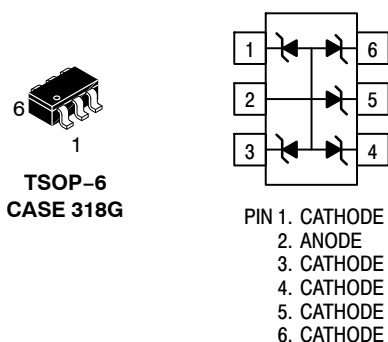


ON Semiconductor®

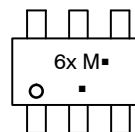
<http://onsemi.com>

TSOP-6 FIVE TRANSIENT VOLTAGE SUPPRESSOR 350 W PEAK POWER

PIN ASSIGNMENT



MARKING DIAGRAM



x = SMS05C:J
= SMS12C:K
= SMS15C:L
= SMS24C:M
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
SMS05CT1G	TSOP-6 (Pb-Free)	3000/Tape & Reel
SMS12CT1G		
SMS15CT1G		
SMS24CT1G		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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SMS05C ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V_{BR}	$I_T = 1.0\text{ mA}$ (Note 3)	6.2		7.2	V
Reverse Leakage Current	I_R	$V_{RWM} = 5.0\text{ V}$			5.0	μA
Clamping Voltage	V_C	$I_{PP} = 5.0\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			9.8	V
Clamping Voltage	V_C	$I_{PP} = 24\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			14.5	V
Maximum Peak Pulse Current	I_{PP}	$8 \times 20\text{ }\mu\text{s}$ Waveform			24	A
Capacitance	C_J	$V_R = 0\text{ V}$, $f = 1.0\text{ MHz}$ (Line to GND)		260	400	pF

SMS12C ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			12	V
Breakdown Voltage	V_{BR}	$I_T = 1.0\text{ mA}$ (Note 3)	13.3		15	V
Reverse Leakage Current	I_R	$V_{RWM} = 12\text{ V}$		0.001	1.0	μA
Clamping Voltage	V_C	$I_{PP} = 5.0\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			19	V
Clamping Voltage	V_C	$I_{PP} = 15\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			23	V
Maximum Peak Pulse Current	I_{PP}	$8 \times 20\text{ }\mu\text{s}$ Waveform			15	A
Capacitance	C_J	$V_R = 0\text{ V}$, $f = 1.0\text{ MHz}$ (Line to GND)		120	150	pF

SMS15C ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise specified) (See Note 4)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			15	V
Breakdown Voltage	V_{BR}	$I_T = 1.0\text{ mA}$ (Note 3)	17		19	V
Reverse Leakage Current	I_R	$V_{RWM} = 15\text{ V}$		0.05	1.0	μA
Clamping Voltage	V_C	$I_{PP} = 5.0\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			24	V
Clamping Voltage	V_C	$I_{PP} = 12\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			29	V
Maximum Peak Pulse Current	I_{PP}	$8 \times 20\text{ }\mu\text{s}$ Waveform			12	A
Capacitance	C_J	$V_R = 0\text{ V}$, $f = 1.0\text{ MHz}$ (Line to GND)		95	125	pF

SMS24C ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			24	V
Breakdown Voltage	V_{BR}	$I_T = 1.0\text{ mA}$ (Note 3)	26.7		32	V
Reverse Leakage Current	I_R	$V_{RWM} = 24\text{ V}$		0.001	1.0	μA
Clamping Voltage	V_C	$I_{PP} = 5.0\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			40	V
Clamping Voltage	V_C	$I_{PP} = 8\text{ A}$ ($8 \times 20\text{ }\mu\text{s}$ Waveform)			44	V
Maximum Peak Pulse Current	I_{PP}	$8 \times 20\text{ }\mu\text{s}$ Waveform			8.0	A
Capacitance	C_J	$V_R = 0\text{ V}$, $f = 1.0\text{ MHz}$ (Line to GND)		60	75	pF

2. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
3. V_{BR} is measured at pulse test current I_T .
4. Parametrics are the same for the Pb-Free packages, which are suffixed with a "G".

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TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise specified)

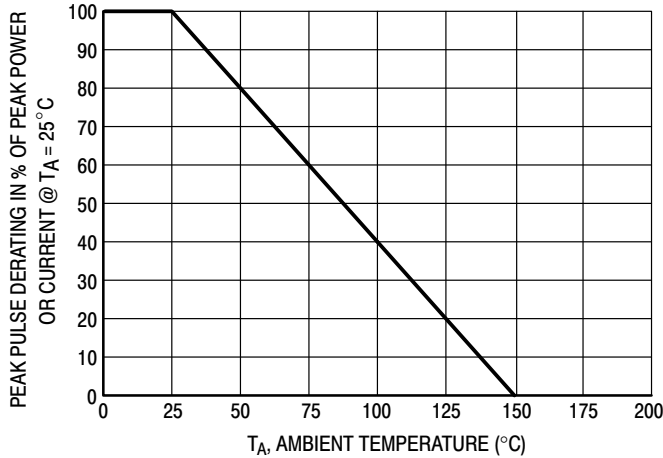


Figure 1. Pulse Derating Curve

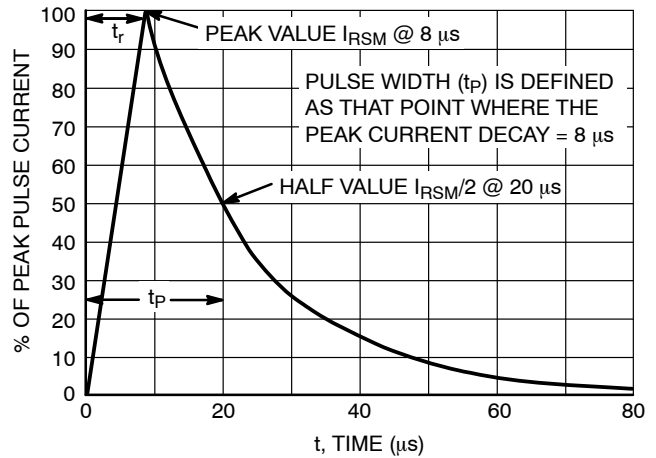


Figure 2. $8 \times 20 \mu\text{s}$ Pulse Waveform

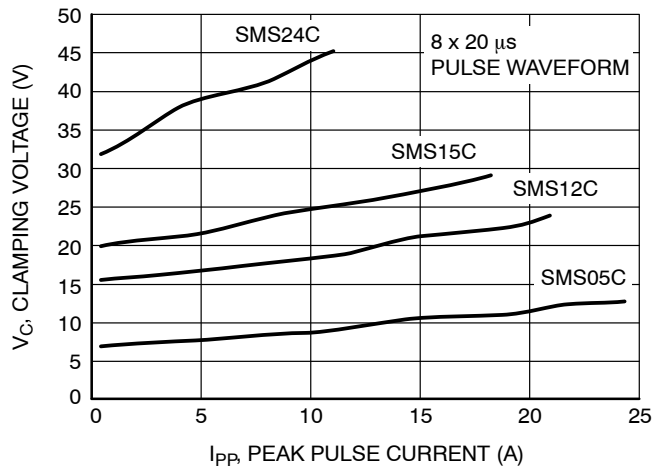


Figure 3. Clamping Voltage vs. Peak Pulse Current

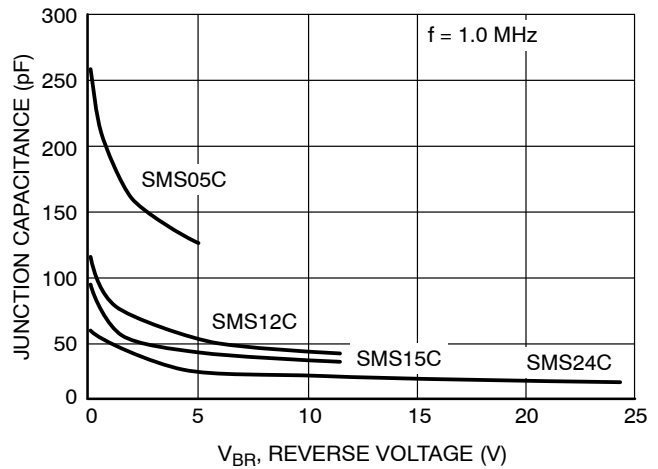


Figure 4. Junction Capacitance vs. Reverse Voltage

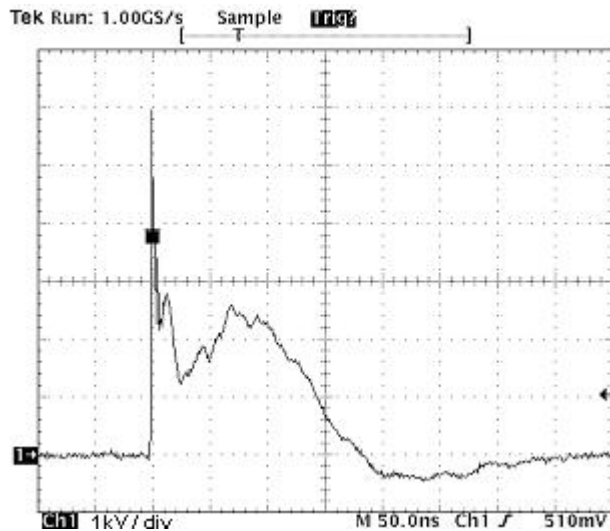


Figure 5. ESD Pulse IEC 61000-4-2 (8.0 kV Contact)

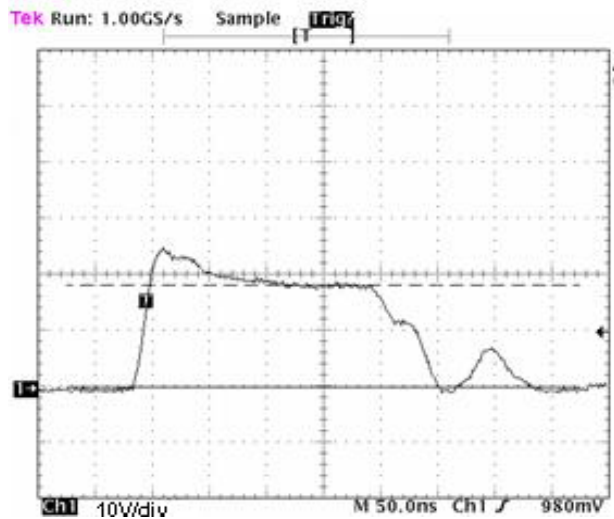


Figure 6. SMS15CT1 ESD Response for IEC 61000-4-2 (+8.0 kV Contact)

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TYPICAL COMMON ANODE APPLICATIONS

A 5 TVS junction common anode design in a TSOP-6 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. A simplified example of SMS05C Series Device applications is illustrated below.

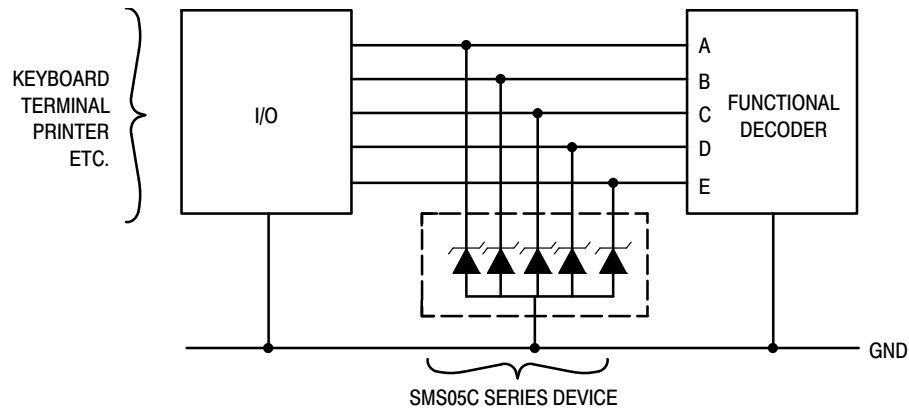


Figure 7. Computer Interface Protection

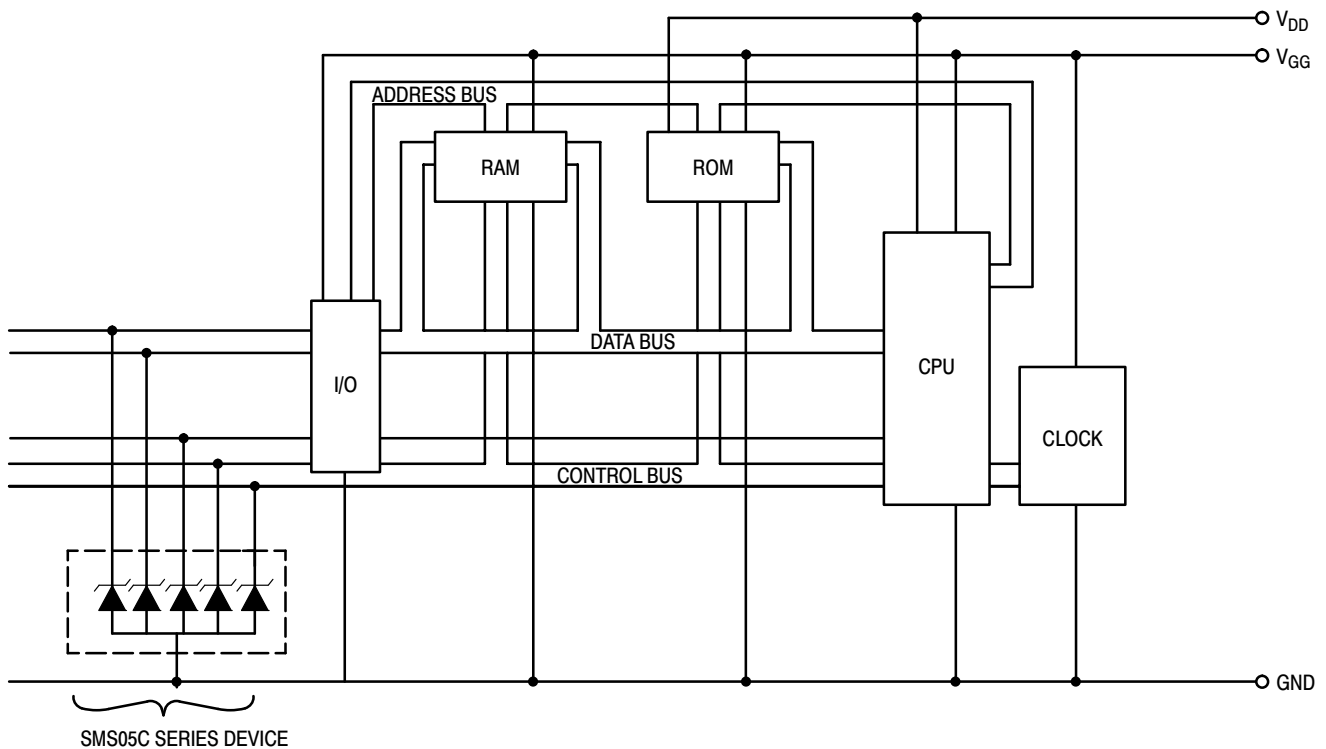
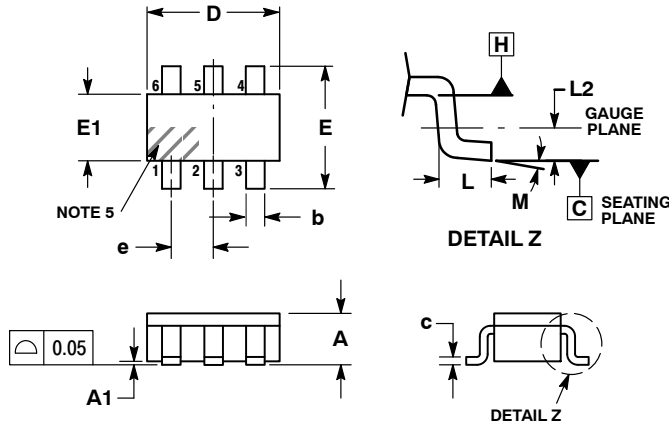


Figure 8. Microprocessor Protection

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PACKAGE DIMENSIONS

TSOP-6 CASE 318G-02 ISSUE U

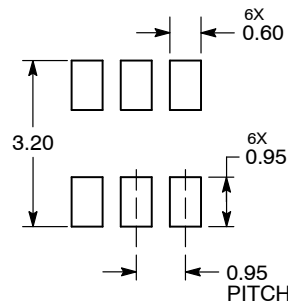


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.01	0.06	0.10
b	0.25	0.38	0.50
c	0.10	0.18	0.26
D	2.90	3.00	3.10
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
e	0.85	0.95	1.05
L	0.20	0.40	0.60
L2	0.25 BSC		
M	0°	-	10°

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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